## NLMD5820

### 2.65 W Filterless Class-D Audio Amplifier with Integrated Dual SPST Switch

The NLMD5820 is an integrated mono Class-D audio power amplifier and dual SPST switch capable of delivering 2.65 W of continuous average power to $4.0 \Omega$ from a 5.0 V supply in a Bridge Tied Load (BTL) configuration. Under the same conditions, the output power stage can provide 1.4 W to a $8.0 \Omega \mathrm{BTL}$ load with less than $1 \%$ THD+N. For cellular handsets or PDAs it offers space and cost savings because no output filter is required when using inductive tranducers. The NLMD5820 incorporates a dual SPST switch which allows signals to bypass the amplifier. The integrated switch operates off a separate supply voltage and maintains a very low $\mathrm{R}_{\mathrm{ON}}$ resistance, $0.5 \Omega$ max @ $2.8 \mathrm{~V}_{\mathrm{CC}}$.

The NLMD5820 processes analog inputs with a pulse width modulation technique that lowers output noise and THD when compared to a conventional sigma-delta modulator. The device allows independent gain while summing signals from various audio sources. Thus, in cellular handsets, the earpiece, the loudspeaker and even the melody ringer can be driven with a single NLMD5820. Due to its low $42 \mu \mathrm{~V}$ noise floor, A-weighted, clean listening is guaranteed no matter the load sensitivity.

## Features

- Optimized PWM Output Stage: Filterless Capability
- Efficiency up to $90 \%$

Low 2.5 mA Typical Quiescent Current

- Large Output Power Capability: 1.4 W with $8.0 \Omega$ Load (CSP) and THD + N $<1 \%$
- Dual SPST with $0.5 \Omega$ Max $\mathrm{R}_{\mathrm{ON}} @ \mathrm{~V}_{\mathrm{CC}}=2.8 \mathrm{~V}$
- High Performance, THD +N of $0.03 \% @ \mathrm{~V}_{\mathrm{p}}=5.0 \mathrm{~V}$,

$$
\mathrm{R}_{\mathrm{L}}=8.0 \Omega, \mathrm{P}_{\text {out }}=100 \mathrm{~mW}
$$

- Excellent PSRR (-65 dB): No Need for Voltage Regulation
- Surface Mounted Package UDFN16
- Fully Differential Design. Eliminates Two Input Coupling Capacitors
- Very Fast Turn On/Off Times with Advanced Rising and Falling Gain Technique
- External Gain Configuration Capability
- Internally Generated 250 kHz Switching Frequency
- Short Circuit Protection Circuitry
- "Pop and Click" Noise Protection Circuitry
- This is a Pb -Free Device


## Applications

- Cellular Phone
- Portable Electronic Devices
- PDAs and Smart Phones


## ON Semiconductor ${ }^{\circledR}$

## http://onsemi.com



## PIN CONNECTIONS



| ORDERING INFORMATION |  |  |
| :---: | :---: | :---: |
| Device | Package | Shipping ${ }^{\dagger}$ |
| NLMD5820MUTAG | $\begin{gathered} 16 \text { PIN } \\ \text { UDFN } \\ \text { (Pb-Free) } \end{gathered}$ | 3000/Tape \& Reel |
| For information on tape and reel specifications, |  |  |
| including part orientation and tape sizes, please |  |  |
| refer to our Tape and Reel Packaging Specification |  |  |
| Brochure, BRD8 |  |  |

## NLMD5820



Figure 1. Functional Block Diagram

FUNCTION TABLE

| IN $\mathbf{1 , 2}$ | NC $\mathbf{1 , 2}$ |
| :---: | :---: |
| 0 | ON |
| 1 | OFF |

## NLMD5820

PIN DESCRIPTION

| Pin No. | Symbol | Type | Description |
| :---: | :---: | :---: | :---: |
| 1 | NC2 | I/O | Normally Closed Signal Line for Switch \#2. |
| 2 | IN2 | I | Control Input for Switch \#2. |
| 3 | COM2 | I/O | Common Signal Line for Switch \#2. |
| 4 | $\mathrm{V}_{\text {CC }}$ | 1 | Analog Supply for Switches. Range: $1.65 \mathrm{~V}-4.5 \mathrm{~V}$. |
| 5 | $\overline{\text { SD }}$ | I | The device enters in Shutdown Mode when a low level is applied on this pin. An internal $300 \mathrm{k} \Omega$ resistor will force the device in shutdown mode if no signal is applied to this pin. It also helps to save space and cost. |
| 6 | $\mathrm{V}_{\mathrm{p}}$ | 1 | Power Analog Positive Supply. Range: $2.5 \mathrm{~V}-5.5 \mathrm{~V}$. |
| 7 | INP | I | Positive Differential Input. |
| 8 | INM | 1 | Negative Differential Input. |
| 9 | OUTP | 0 | Positive BTL Output. |
| 10 | $\mathrm{V}_{\mathrm{p}}$ | 1 | Analog Positive Supply. Range: $2.5 \mathrm{~V}-5.5 \mathrm{~V}$. |
| 11 | GND | I | Analog Ground. |
| 12 | OUTM | 0 | Negative BTL Output. |
| 13 | COM1 | I/O | Common Signal Line for Switch \#1. |
| 14 | IN1 | 1 | Control Input for Switch \#1. |
| 15 | NC1 | I/O | Normally Closed Signal Line for Switch \#1. |
| 16 | GND | 1 | Analog Ground. |

## NLMD5820

MAXIMUM RATINGS

| Symbol | Rating | Max | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{p}}$ | Supply Voltage for Amplifier $\begin{gathered}\text { Active Mode } \\ \text { Shutdown Mode }\end{gathered}$ | $\begin{aligned} & 6.0 \\ & 7.0 \end{aligned}$ | V |
| $V_{\text {in }}$ | Input Voltage for Amplifier | -0.3 to $\mathrm{V}_{\mathrm{CC}}+0.3$ | V |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply Voltage for Switches | -0.5 to +5.5 | V |
| $\mathrm{V}_{\text {IS }}$ | Analog Signal Voltage for Switches ( $\mathrm{V}_{\mathrm{NC}}$, or $\mathrm{V}_{\text {COM }}$ ) | $-0.5 \leq \mathrm{V}_{\text {IS }} \leq \mathrm{V}_{\mathrm{CC}}+0.5$ | V |
| $\mathrm{V}_{\text {IN }}$ | Control Input for Switches | $-0.5 \leq \mathrm{V}_{\text {IN }} \leq+5.5$ | V |
| $\mathrm{I}_{\text {out }}$ | Max Output Current of Amplifier (Note 1) | 1.5 | A |
| $\mathrm{l}_{\text {anl1 }}$ | Continuous DC Current from COM to NC | $\pm 300$ | mA |
| lanl-pk1 | Peak Current from COM to NC, 10 Duty Cycle | $\pm 500$ | mA |
| $I_{\text {clmp }}$ | Continuous DC Current into COM/NC with Respect to $\mathrm{V}_{\text {CC }}$ or GND | $\pm 100$ | mA |
| $\mathrm{P}_{\mathrm{d}}$ | Power Dissipation (Note 2) | Internally Limited | - |
| $\mathrm{T}_{J}$ | Max Junction Temperature | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature Range | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{R}_{\text {өJA }}$ | Thermal Resistance Junction-to-Air UDFN16 | 50 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| - | ESD Protection <br> Human Body Model (HBM) (Note 3) <br> Machine Model (MM) (Note 4) | $\begin{gathered} >2000 \\ >200 \end{gathered}$ | V |
| - | Latchup Current @ $\mathrm{T}_{\mathrm{A}}=85^{\circ} \mathrm{C}$ (Note 5) UDFN16 | $\pm 100$ | mA |
| MSL | Moisture Sensitivity (Note 6) | Level 1 |  |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The device is protected by a current breaker structure. See "Current Breaker Circuit" in the Description Information section for more information.
2. The thermal shutdown is set to $160^{\circ} \mathrm{C}$ (typical) avoiding irreversible damage to the device due to power dissipation.
3. Human Body Model: 100 pF discharged through a $1.5 \mathrm{k} \Omega$ resistor following specification JESD22/A114.
4. Machine Model: 200 pF discharged through all pins following specification JESD22/A115.
5. Latchup Testing per JEDEC Standard JESD78.
6. Moisture Sensitivity Level (MSL): 1 per IPC/JEDEC standard: J-STD-020A.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Range | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{P}}$ | Supply Voltage for Amplifier | 2.5 to 5.5 | V |
| $\mathrm{~V}_{\mathrm{CC}}$ | Supply Voltage for Switches | 1.65 to 4.5 | V |
| $\mathrm{~V}_{\mathrm{IS}}$ | Analog Signal Voltage for Switches | GND to $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{V}_{\mathrm{IN}}$ | Control Input for Switches | GND to $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Ambient Temperature | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |

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ELECTRICAL CHARACTERISTICS OF AMPLIFIER (Limits apply for $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ unless otherwise noted)

| Characteristic | Symbol | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Quiescent Current | $\mathrm{I}_{\mathrm{dd}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8.0 \Omega \\ & \mathrm{~V}_{\mathrm{p}}=5.5 \mathrm{~V} \text {, No Load } \end{aligned}$ <br> $\mathrm{V}_{\mathrm{p}}$ from 2.5 V to 5.5 V , No Load $\mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}$ |  | $\begin{aligned} & 2.15 \\ & 2.61 \end{aligned}$ | $3.8$ | mA |
| Shutdown Current | $I_{\text {sd }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{p}}=4.2 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{A}}=+85^{\circ} \mathrm{C} \end{aligned}$ |  | $\begin{aligned} & 0.42 \\ & 0.45 \end{aligned}$ | $\begin{aligned} & 0.8 \\ & 2.0 \end{aligned}$ | $\mu \mathrm{A}$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{p}}=5.5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{A}}=+85^{\circ} \mathrm{C} \end{aligned}$ |  | $\begin{aligned} & 0.8 \\ & 0.9 \end{aligned}$ | $1.5$ | $\mu \mathrm{A}$ |
| Shutdown Voltage High | $\mathrm{V}_{\text {sdih }}$ | - | 1.2 | - | - | V |
| Shutdown Voltage Low | $V_{\text {sdil }}$ | - | - | - | 0.4 | V |
| Switching Frequency | $\mathrm{F}_{\text {sw }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{p}} \text { from } 2.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \end{aligned}$ | 180 | 240 | 300 | kHz |
| Gain | G | $\mathrm{R}_{\mathrm{L}}=8.0 \Omega$ | $\frac{285 \mathrm{k} \Omega}{\mathrm{R}_{\mathrm{i}}}$ | $\frac{300 \mathrm{k} \Omega}{\mathrm{R}_{\mathrm{i}}}$ | $\frac{315 \mathrm{k} \Omega}{\mathrm{R}_{\mathrm{i}}}$ | $\stackrel{\mathrm{V}}{\mathrm{V}}$ |
| Output Impedance in Shutdown Mode | $\mathrm{Z}_{\text {SD }}$ | - | - | 20 | - | $\mathrm{k} \Omega$ |
| Resistance from SD to GND | Rs | - | - | 300 | - | k $\Omega$ |
| Output Offset Voltage | Vos | $\mathrm{V}_{\mathrm{p}}=5.5 \mathrm{~V}$ | - | 6.0 | - | mV |
| Turn On Time | Ton | $\mathrm{V}_{\mathrm{p}}$ from 2.5 V to 5.5 V | - | 1.0 | - | us |
| Turn Off Time | Toff | $\mathrm{V}_{\mathrm{p}}$ from 2.5 V to 5.5 V | - | 1.0 | - | us |
| Thermal Shutdown Temperature | Tsd | - | - | 160 | - | ${ }^{\circ} \mathrm{C}$ |
| Output Noise Voltage | Vn | $\begin{gathered} \hline \mathrm{V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{f}=20 \mathrm{~Hz} \text { to } 20 \mathrm{kHz} \\ \text { no weighting filter } \\ \text { with A weighting filter } \end{gathered}$ |  | $\begin{aligned} & 65 \\ & 42 \end{aligned}$ |  | $\mu \mathrm{Vrms}$ |
| RMS Output Power | Po | $\begin{gathered} \hline \mathrm{R}_{\mathrm{L}}=8.0 \Omega, \mathrm{f}=1.0 \mathrm{kHz}, \mathrm{THD}+\mathrm{N}<1 \% \\ \mathrm{~V}_{\mathrm{p}}=2.5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}}=3.0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}}=3.6 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}}=4.2 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}}=5.0 \mathrm{~V} \end{gathered}$ | - - - | $\begin{aligned} & 0.22 \\ & 0.33 \\ & 0.45 \\ & 0.67 \\ & 0.92 \end{aligned}$ |  | W |
|  |  | $\begin{array}{rl} \mathrm{R}_{\mathrm{L}}=8.0 \Omega, \mathrm{f}=1.0 \mathrm{kHz}, \mathrm{THD}+\mathrm{N}<10 \% \\ \mathrm{~V}_{\mathrm{p}} & =2.5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}} & =3.0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}} & =4.6 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}} & 4.2 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}} & =5.0 \mathrm{~V} \end{array}$ |  | $\begin{aligned} & 0.36 \\ & 0.53 \\ & 0.76 \\ & 1.07 \\ & 1.49 \end{aligned}$ |  | W |
|  |  | $\begin{gathered} \mathrm{R}_{\mathrm{L}}=4.0 \Omega, \mathrm{f}=1.0 \mathrm{kHz}, \mathrm{THD}+\mathrm{N}<1 \% \\ \mathrm{~V}_{\mathrm{p}}=2.5 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}}=3.0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}}=3.6 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}}=5.2 \mathrm{~V} \\ \end{gathered}$ |  | $\begin{aligned} & 0.24 \\ & 0.38 \\ & 0.57 \\ & 0.83 \\ & 1.2 \end{aligned}$ |  | W |
|  |  | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=4.0 \Omega, \mathrm{f}=1.0 \mathrm{kHz}, \mathrm{THD}+\mathrm{N}<10 \% \\ & \mathrm{~V}_{\mathrm{p}}=2.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{p}}=3.0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{p}}=3.6 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{p}}=4.2 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{p}}=5.0 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 0.52 \\ 0.8 \\ 1.125 \\ 1.58 \\ 2.19 \end{gathered}$ |  | W |
| Efficiency | - | $\begin{array}{r} \mathrm{R}_{\mathrm{L}}=8.0 \Omega, \mathrm{f}=1.0 \mathrm{kHz} \\ \mathrm{~V}_{\mathrm{p}}=5.0 \mathrm{~V}, \mathrm{P}_{\text {out }}=1.2 \mathrm{~W} \\ \mathrm{~V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{P}_{\text {out }}=0.6 \mathrm{~W} \end{array}$ |  | $\begin{aligned} & 87 \\ & 87 \end{aligned}$ |  | \% |
|  |  | $\begin{gathered} \mathrm{R}_{\mathrm{L}}=4.0 \Omega, \mathrm{f}=1.0 \mathrm{kHz} \\ \mathrm{~V}_{\mathrm{p}}=5.0 \mathrm{~V}, \mathrm{P}_{\text {out }}=2.0 \mathrm{~W} \\ \mathrm{~V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{P}_{\text {out }}=1.0 \mathrm{~W} \end{gathered}$ |  | $\begin{aligned} & 79 \\ & 78 \end{aligned}$ | - |  |

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ELECTRICAL CHARACTERISTICS OF AMPLIFIER (Limits apply for $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ unless otherwise noted)

| Characteristic | Symbol | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Total Harmonic Distortion + Noise | THD+N | $\begin{gathered} \mathrm{V}_{\mathrm{p}}=5.0 \mathrm{~V}, R_{L}=8.0 \Omega, \\ \mathrm{f}=1.0 \mathrm{kHz}, \mathrm{P}_{\text {out }}=0.25 \mathrm{~W} \\ \mathrm{~V}_{\mathrm{p}}=3.6 \mathrm{~V}, R_{L}=8.0 \Omega, \\ \mathrm{f}=1.0 \mathrm{kHz}, \mathrm{P}_{\text {out }}=0.25 \mathrm{~W} \end{gathered}$ |  | $\begin{aligned} & 0.05 \\ & 0.06 \end{aligned}$ |  | \% |
| Common Mode Rejection Ratio | CMRR | $\begin{gathered} \mathrm{V}_{\mathrm{p}} \text { from } 2.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ \mathrm{~V}_{\text {ic }}=0.5 \mathrm{~V} \text { to } \mathrm{V}_{\mathrm{p}}-0.8 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{~V}_{\text {ic }}=1.0 \mathrm{~V} \mathrm{pp} \\ \mathrm{f}=217 \mathrm{~Hz} \\ \mathrm{f}=1.0 \mathrm{kHz} \end{gathered}$ | - | $\begin{aligned} & -62 \\ & -56 \\ & -57 \end{aligned}$ | - | dB |
| Power Supply Rejection Ratio | PSRR | $\begin{gathered} \mathrm{V}_{\text {P_ripple_pk-pk }}=200 \mathrm{mV}, R_{\mathrm{L}}=8.0 \Omega, \\ \text { Inputs } A C \mathrm{Grounded} \\ \mathrm{~V}_{\mathrm{p}}=3.6 \mathrm{~V} \\ \mathrm{f}=217 \mathrm{kHz} \\ \mathrm{f}=1.0 \mathrm{kHz} \end{gathered}$ |  | $\begin{aligned} & -62 \\ & -65 \end{aligned}$ |  | dB |

DC ELECTRICAL CHARACTERISTICS OF SWITCHES

| Characteristic | Symbol | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Control Input High Voltage | $\mathrm{V}_{\mathrm{IH}}$ | $\begin{aligned} & \hline \mathrm{VCC}=3.0 \mathrm{~V} \\ & \mathrm{VCC}=4.2 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & 1.4 \\ & 2.0 \end{aligned}$ |  |  | V |
| Control Input Low Voltage | $\mathrm{V}_{\text {IL }}$ | $\begin{aligned} & \mathrm{VCC}=3.0 \mathrm{~V} \\ & \mathrm{VCC}=4.2 \mathrm{~V} \end{aligned}$ |  |  | $\begin{aligned} & 0.7 \\ & 0.8 \end{aligned}$ | V |
| Control Input Leakage Current | IN | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {CC }}$ or GND |  | $\pm 0.1$ | $\pm 1.0$ | $\mu \mathrm{A}$ |
| ON State Leakage Current | I'COM(ON) | $0 \mathrm{~V}<\mathrm{V}_{\mathrm{COM}}, \mathrm{V}_{\mathrm{NC}}<\mathrm{V}_{\mathrm{CC}}$ |  | $\pm 10$ | $\pm 100$ | nA |
| OFF State Leakage Current | $\mathrm{I}_{\text {NC(OFF) }}$ | $0 \mathrm{~V}<\mathrm{V}_{\mathrm{COM}}, \mathrm{V}_{\mathrm{NC}}<\mathrm{V}_{\mathrm{CC}}$ |  | $\pm 5$ | $\pm 50$ | nA |
| Quiescent Current | ICC | All Channels ON or OFF, <br> $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}$ or $G N D$, IOUT $=0$ |  | $\pm 1.0$ | $\pm 2.0$ | $\mu \mathrm{A}$ |
| ON Resistance | $\mathrm{R}_{\mathrm{ON}}$ | $\begin{aligned} & \hline \mathrm{VCC}=3.0 \mathrm{~V} \\ & \mathrm{VCC}=4.2 \mathrm{~V} \end{aligned}$ |  | $\begin{gathered} 0.4 \\ 0.35 \end{gathered}$ | $\begin{aligned} & 0.5 \\ & 0.4 \end{aligned}$ | $\begin{aligned} & \bar{\Omega} \\ & \Omega \end{aligned}$ |
| R ${ }_{\text {ON }}$ Flatness | $\mathrm{R}_{\text {FLAT }}$ | $\begin{aligned} & \mathrm{VCC}=3.0 \mathrm{~V} \\ & \mathrm{VCC}=4.2 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.16 \\ & 0.11 \end{aligned}$ | $\begin{aligned} & 0.20 \\ & 0.14 \end{aligned}$ | $\begin{aligned} & \Omega \\ & \Omega \end{aligned}$ |
| RON Matching | $\Delta \mathrm{R}_{\mathrm{ON}}$ | $\begin{aligned} & \hline \mathrm{VCC}=3.0 \mathrm{~V} \\ & \mathrm{VCC}=4.2 \mathrm{~V} \end{aligned}$ |  | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & 0.05 \\ & 0.05 \end{aligned}$ | $\begin{aligned} & \bar{\Omega} \\ & \Omega \end{aligned}$ |

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AC ELECTRICAL CHARACTERISTICS OF SWITCHES (Input $t_{r}=t_{f}=3.0 \mathrm{~ns}$ )

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\mathrm{ON}}$ | Turn-On Time | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ (Figures 43 and 44) |  | 50 |  | ns |
| toff | Turn-Off Time | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}$ (Figures 43 and 44) |  | 30 |  | ns |
| $\mathrm{C}_{\text {IN }}$ | Control Pin Input Capacitance | $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ |  | 3.5 |  | pF |
| $\mathrm{C}_{\mathrm{NC}}$ | NC Port Capacitance | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {IN }}=0 \mathrm{~V}$ |  | 60 |  | pF |
| $\mathrm{C}_{\text {COM }}$ | COM Port Capacitance When Switch is Enabled | $\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}$ |  | 200 |  | pF |
| BW | Maximum On-Channel -3 dB Bandwidth or Minimum Frequency Response | $\mathrm{V}_{\text {IN }}$ centered between $\mathrm{V}_{\mathrm{CC}}$ and GND (Figure 45) |  | 19 |  | MHz |
| $\mathrm{V}_{\text {ONL }}$ | Maximum Feed-through On Loss | $\mathrm{V}_{\mathrm{IN}}=0 \mathrm{dBm} @ 100 \mathrm{kHz}$ to 50 MHz <br> $\mathrm{V}_{\text {IN }}$ centered between $\mathrm{V}_{\mathrm{CC}}$ and GND (Figure 45) |  | -0.06 |  | dB |
| VISO | Off-Channel Isolation | $\begin{array}{\|l} \hline f=100 \mathrm{kHz} ; \mathrm{V}_{\mathrm{IS}}=1 \mathrm{~V} \text { RMS; } \mathrm{C}_{\mathrm{L}}=5.0 \mathrm{pF} \\ \mathrm{~V}_{\text {IN }} \text { centered between } \mathrm{V}_{\mathrm{CC}} \text { and } \text { GND (Figure 45) } \end{array}$ |  | -68 |  | dB |
| Q | Charge Injection Select Input to Common I/O | $\begin{aligned} & \mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}} \text { to } \mathrm{GND}, \mathrm{R}_{\text {IS }}=0 \Omega, \mathrm{C}_{\mathrm{L}}=1.0 \mathrm{nF} \\ & \mathrm{Q}=\mathrm{C}_{\mathrm{L}} \times \mathrm{DV}_{\text {OUT }} \text { (Figure 46) } \end{aligned}$ |  | 38 |  | pC |
| THD | Total Harmonic Distortion THD + Noise | $\begin{aligned} & \mathrm{F}_{\mathrm{IS}}=20 \mathrm{~Hz} \text { to } 20 \mathrm{kHz}, \mathrm{R}_{\mathrm{L}}=\mathrm{R}_{\text {gen }}=600 \Omega, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{~V}_{\mathrm{IS}}=2.0 \mathrm{~V} \text { RMS } \end{aligned}$ |  | 0.08 |  | \% |
| VCT | Channel-to-Channel Crosstalk | $\mathrm{f}=100 \mathrm{kHz} ; \mathrm{V}_{\mathrm{IS}}=1.0 \mathrm{~V} \text { RMS, } \mathrm{C}_{\mathrm{L}}=5.0 \mathrm{pF}, \mathrm{R}_{\mathrm{L}}=50 \Omega$ <br> $\mathrm{V}_{\mathrm{IN}}$ centered between $\mathrm{V}_{\mathrm{CC}}$ and GND (Figure 45) |  | -70 |  | dB |



Figure 2. Test Setup for Typical Characteristics (Figures 3 - 34)

## NOTES:

1. Unless otherwise noted, $C_{i}=100 \mathrm{nF}$ and $\mathrm{R}_{\mathrm{i}}=150 \mathrm{k} \Omega$. Thus, the gain setting is $2 \mathrm{~V} / \mathrm{V}$ and the cutoff frequency of the input high pass filter is set to 10 Hz . Input capacitors are shorted for CMRR measurements.
2. To closely reproduce a real application case, all measurements are performed using the following loads:
$\mathrm{R}_{\mathrm{L}}=8 \Omega$ means Load $=15 \mu \mathrm{H}+8 \Omega+15 \mu \mathrm{H}$
$\mathrm{R}_{\mathrm{L}}=4 \Omega$ means Load $=15 \mu \mathrm{H}+4 \Omega+15 \mu \mathrm{H}$
Very low DCR $15 \mu \mathrm{H}$ inductors ( $50 \mathrm{~m} \Omega$ ) have been used for the following graphs. Thus, the electrical load measurements are performed on the resistor $(8 \Omega$ or $4 \Omega)$ in differential mode.
3. For Efficiency measurements, the optional 30 kHz filter is used. An RC low-pass filter is selected with ( $100 \Omega, 47 \mathrm{nF}$ ) on each PWM output.

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## TYPICAL CHARACTERISTICS OF AMPLIFIER



Figure 3. Efficiency vs. $\mathrm{P}_{\text {out }}$ $\mathrm{V}_{\mathrm{p}}=5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{f}=\mathbf{1 k H z}$


Figure 5. Efficiency vs. $\mathrm{P}_{\text {out }}$ $\mathrm{V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{f}=\mathbf{1} \mathrm{kHz}$


Figure 7. Efficiency vs. Pout $V_{p}=5 \mathrm{~V}, R_{L}=4 \Omega, f=1 \mathrm{kHz}$


Figure 4. Die Temperature vs. $P_{\text {out }}$ $\mathrm{V}_{\mathrm{p}}=5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{f}=1 \mathrm{kHz} @ \mathrm{~T}_{\mathrm{A}}=+\mathbf{2 5}^{\circ} \mathrm{C}$


Figure 6. Die Temperature vs. P out $\mathrm{V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{f}=1 \mathrm{kHz} @ \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$


Figure 8. Die Temperature vs. $P_{\text {out }}$ $\mathrm{V}_{\mathrm{p}}=5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=4 \Omega, \mathrm{f}=1 \mathrm{kHz} @ \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$

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TYPICAL CHARACTERISTICS OF AMPLIFIER


Figure 9. Efficiency vs. $\mathrm{P}_{\text {out }}$ $\mathrm{V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=4 \Omega, \mathrm{f}=1 \mathrm{kHz}$


Figure 11. THD+N vs. $\mathrm{P}_{\text {out }}$ $\mathrm{V}_{\mathrm{p}}=5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{f}=1 \mathrm{kHz}$


Figure 13. THD+N vs. $\mathrm{P}_{\text {out }}$ $\mathrm{V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{f}=1 \mathrm{kHz}$


Figure 10. Die Temperature vs. $\mathrm{P}_{\text {out }}$ $\mathrm{V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=4 \Omega, \mathrm{f}=1 \mathrm{kHz} @ \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$


Figure 12. THD+N vs. $\mathrm{P}_{\text {out }}$ $V_{p}=4.2 \mathrm{~V}, R_{L}=8 \Omega, f=1 \mathrm{kHz}$


Figure 14. THD+N vs. $\mathrm{P}_{\text {out }}$ $\mathrm{V}_{\mathrm{p}}=3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=\mathbf{8} \Omega, \mathrm{f}=\mathbf{1} \mathrm{kHz}$

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Figure 15. THD $+N$ vs. Pout $\mathrm{V}_{\mathrm{p}}=2.5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{f}=\mathbf{1} \mathrm{kHz}$


Figure 17. THD $+N$ vs. Pout $\mathrm{V}_{\mathrm{p}}=4.2 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=4 \Omega, \mathrm{f}=1 \mathrm{kHz}$


Figure 19. THD $+N$ vs. Power Out $V_{p}=3 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=4 \Omega, \mathrm{f}=1 \mathrm{kHz}$


Figure 16. THD $+N$ vs. Pout $V_{p}=5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=4 \Omega, \mathrm{f}=1 \mathrm{kHz}$


Figure 18. THD+N vs. Pout $\mathrm{V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=4 \Omega, \mathrm{f}=1 \mathrm{kHz}$


Figure 20. THD+N vs. Power Out $\mathrm{V}_{\mathrm{p}}=2.5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=4 \Omega, \mathrm{f}=1 \mathrm{kHz}$

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TYPICAL CHARACTERISTICS OF AMPLIFIER


Figure 21. Output Power vs. Power Supply
$R_{L}=8 \Omega @ f=1 \mathrm{kHz}$


Figure 23. THD+N vs. Frequency $R_{L}=8 \Omega, P_{\text {out }}=250 \mathrm{~mW} @ \mathrm{f}=\mathbf{1} \mathrm{kHz}$


Figure 25. PSRR vs. Frequency
Inputs Grounded, $\mathrm{R}_{\mathrm{L}}=8 \Omega$, Vripple $=\mathbf{2 0 0}$ mvpkpk


Figure 22. Output Power vs. Power Supply $R_{L}=4 \Omega @ f=1 \mathrm{kHz}$


Figure 24. THD+N vs. Frequency $R_{L}=4 \Omega, P_{\text {out }}=250 \mathrm{~mW} @ \mathrm{f}=1 \mathrm{kHz}$


Figure 26. PSRR vs. Frequency
Inputs grounded, $R_{L}=4 \Omega$, Vripple $=200 \mathrm{mVpkpk}$

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## TYPICAL CHARACTERISTICS OF AMPLIFIER



Figure 27. PSRR vs. Frequency $\mathrm{V}_{\mathrm{p}}=3.6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8 \Omega$, Vic = 200 mvpkpk


Figure 29. Shutdown Current vs. Power Supply $\mathbf{R}_{\mathrm{L}}=8 \Omega$


Figure 31. Noise Floor, Inputs AC Grounded with $1 \mu \mathrm{~F} \mathrm{~V}_{\mathrm{p}}=3.6 \mathrm{~V}$


Figure 28. Thermal Shutdown vs. Temperature $\mathrm{V}_{\mathrm{p}}=5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=8 \Omega$,


Figure 30. Quiescent Current vs. Power Supply $R_{L}=8 \Omega$


Figure 32. Noise Floor, Inputs AC Grounded with $1 \mu \mathrm{~F} \mathrm{~V}_{\mathrm{p}}=5 \mathrm{~V}$

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TYPICAL CHARACTERISTICS OF AMPLIFIER


Figure 33. Turn on Time


Figure 34. Turn off Time

## TYPICAL CHARACTERISTICS OF SWITCHES



Figure 35. Cross Talk vs. Frequency @ $\mathrm{V}_{\mathrm{Cc}}=4.2 \mathrm{~V}$


Figure 36. Bandwidth vs. Frequency

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## TYPICAL CHARACTERISTICS OF SWITCHES



Figure 37. Total Harmonic Distortion


Figure 39. On-Resistance vs. Input Voltage @ $\mathrm{V}_{\mathrm{CC}}=4.2 \mathrm{~V}$


Figure 38. On-Resistance vs. Input Voltage @ $\mathrm{V}_{\mathrm{Cc}}=3.0 \mathrm{~V}$


Figure 40. On-Resistance vs. Input Voltage


Figure 41. Isolation vs. Frequency

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Figure 42. $\mathrm{t}_{\mathrm{BBM}}$ (Time Break-Before-Make)


Figure 43. $\mathrm{t}_{\mathrm{ON}} / \mathrm{t}_{\mathrm{OFF}}$


Figure 44. $\mathrm{t}_{\mathrm{ON}} / \mathrm{t}_{\mathrm{OFF}}$


Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. $\mathrm{V}_{\text {ISO }}$, Bandwidth and $\mathrm{V}_{\text {ONL }}$ are independent of the input signal direction.
$\mathrm{V}_{\text {ISO }}=$ Off Channel Isolation $=20 \log \left(\frac{\mathrm{VOUT}}{\mathrm{V}_{\text {IN }}}\right)$ for $\mathrm{V}_{\text {IN }}$ at 100 kHz
$\mathrm{V}_{\mathrm{ONL}}=$ On Channel Loss $=20 \log \left(\frac{\mathrm{~V}_{\mathrm{OUT}}}{\mathrm{V}_{\mathrm{IN}}}\right)$ for $\mathrm{V}_{\text {IN }}$ at 100 kHz to 50 MHz
Bandwidth (BW) = the frequency 3 dB below $\mathrm{V}_{\mathrm{ONL}}$
$\mathrm{V}_{\mathrm{CT}}=$ Use $\mathrm{V}_{\text {ISO }}$ setup and test to all other switch analog input/outputs terminated with $50 \Omega$

Figure 45. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V ${ }_{\text {ONL }}$


Figure 46. Charge Injection: (Q)

## NLMD5820

## DESCRIPTION INFORMATION

## Detailed Description

The basic structure of the amplifier portion of the NLMD5820 is composed of one analog pre-amplifier, a pulse width modulator and an H-bridge CMOS power stage. The first stage is externally configurable with gain-setting resistor $R_{i}$ and the internal fixed feedback resistor $R_{f}$ (the closed-loop gain is fixed by the ratios of these resistors) and the other stage is fixed. The load is driven differentially through two output stages.

The differential PWM output signal is a digital image of the analog audio input signal. The human ear is a band pass filter regarding acoustic waveforms, the typical values of which are 20 Hz and 20 kHz . Thus, the user will hear only the amplified audio input signal within the frequency range. The switching frequency and its harmonics are fully filtered. The inductive parasitic element of the loudspeaker helps to guarantee a superior distortion value.

## Power Amplifier

The output PMOS and NMOS transistors of the amplifier have been designed to deliver the output power of the specifications without clipping. The channel resistance ( $\mathrm{R}_{\text {on }}$ ) of the NMOS and PMOS transistors is typically $0.4 \Omega$.

## Turn On and Turn Off Transitions in Case of 9 Pin Flip-Chip Package

In order to eliminate "pop and click" noises during transition, the output power in the load must not be established or cutoff suddenly. When a logic high is applied to the shutdown pin, the internal biasing voltage rises quickly and, 4 ms later, once the output DC level is around the common mode voltage, the gain is established slowly $(5.0 \mathrm{~ms})$. This method to turn on the device is optimized in terms of rejection of "pop and click" noises. Thus, the total turn on time to get full power to the load is 9 ms (typical).

The device has the same behavior when it is turned-off by a logic low on the shutdown pin. No power is delivered to the load 5 ms after a falling edge on the shutdown pin. Due to
the fast turn on and off times, the shutdown signal can be used as a mute signal as well.

## Turn On and Turn Off Transitions in Case of UDFN8

In case of UDFN8 package, the audio signal is established instantaneously after the rising edge on the shutdown pin. The audio is also suddenly cut once a low level is sent to the amplifier. This way to turn on and off the device in a very fast way also prevents from "pop \& click" noise.

## Shutdown Function

The device enters shutdown mode when the shutdown signal is low. During the shutdown mode, the DC quiescent current of the circuit does not exceed $1.5 \mu \mathrm{~A}$.

## Current Breaker Circuit

The maximum output power of the circuit corresponds to an average current in the load of 820 mA .

In order to limit the excessive power dissipation in the load if a short-circuit occurs, a current breaker cell shuts down the output stage. The current in the four output MOS transistors are real-time controlled, and if one current exceeds the threshold set to 1.5 A , the MOS transistor is opened and the current is reduced to zero. As soon as the short-circuit is removed, the circuit is able to deliver the expected output power.

This patented structure protects the NLMD5820. Since it completely turns off the load, it minimizes the risk of the chip overheating which could occur if a soft current limiting circuit was used.

## Dual SPST Switch

The NLMD5820 features an integrated dual SPST analog switch. The control for the switch is operated independently of the amplifier, allowing the audio system a choice between routing signals through the amplifier or letting them pass unaffected through the switch. When the switch is open, it maintains significant off isolation to minimize the effects of the amplifier output on the system.

## NLMD5820

## APPLICATION INFORMATION

## NLMD5820 PWM Modulation Scheme

The NLMD5820 uses a PWM modulation scheme with each output switching from 0 to the supply voltage. If $\mathrm{V}_{\text {in }}=$ 0 V outputs OUTM and OUTP are in phase and no current is flowing through the differential load. When a positive
signal is applied, OUTP duty cycle is greater than $50 \%$ and OUTM is less than $50 \%$. With this configuration, the current through the load is 0 A most of the switching period and thus power losses in the load are lowered.


Figure 47. Output Voltage and Current Waveforms into an Inductive Loudspeaker DC Output Positive Voltage Configuration

## Voltage Gain

The first stage is an analog amplifier. The second stage is a comparator: the output of the first stage is compared with a periodic ramp signal. The output comparator gives a pulse width modulation signal (PWM). The third and last stage is the direct conversion of the PWM signal with MOS transistors H -bridge into a powerful output signal with low impedance capability.

With an $8 \Omega$ load, the total gain of the device is typically set to:

$$
\frac{300 \mathrm{k} \Omega}{\mathrm{R}_{\mathrm{i}}}
$$

## Input Capacitor Selection ( $\mathrm{C}_{\mathrm{in}}$ )

The input coupling capacitor blocks the DC voltage at the amplifier input terminal. This capacitor creates a high-pass filter with $\mathrm{R}_{\mathrm{in}}$, the cut-off frequency is given by $\mathrm{Fc}=\frac{1}{2 \times \pi \times \mathrm{R}_{\mathrm{i}} \times \mathrm{C}_{\mathrm{i}}}$.

When using an input resistor set to $150 \mathrm{k} \Omega$, the gain configuration is $2 \mathrm{~V} / \mathrm{V}$. In such a case, the input capacitor selection can be from 10 nF to $1 \mu \mathrm{~F}$ with cutoff frequency values between 1 Hz and 100 Hz . The NLMD5820 also includes a built in low pass filtering function. It's cut off frequency is set to 20 kHz .

## Optional Output Filter

This filter is optional due to the capability of the speaker to filter by itself the high frequency signal. Nevertheless, the high frequency is not audible and filtered by the human ear.

An optional filter can be used for filtering high frequency signal before the speaker. In this case, the circuit consists of two inductors $(15 \mu \mathrm{H})$ and two capacitors $(2.2 \mu \mathrm{~F})$. The size of the inductors is linked to the output power requested by the application. A simplified version of this filter requires a $1 \mu \mathrm{~F}$ capacitor in parallel with the load, instead of two $2.2 \mu \mathrm{~F}$ connected to ground).

Cellular phones and portable electronic devices are great applications for Filterless Class-D as the track length between the amplifier and the speaker is short, thus, there is usually no need for an EMI filter. However, to lower radiated emissions as much as possible when used in filterless mode, a ferrite filter can often be used. Select a ferrite bead with the high impedance around 100 MHz and a very low DCR value in the audio frequency range is the best choice. The MPZ1608S221A1 from TDK is a good choice. The package size is 0603 .

## Optimum Equivalent Capacitance at Output Stage

If the optional filter described in the above section isn't selected. Cellular phones and wireless portable devices design normally put several Radio Frequency filtering capacitors and ESD protection devices between Filter less Class D outputs and loudspeaker. Those devices are usually connected between amplifier output and ground. In order to achieve the best sound quality, the optimum value of total equivalent capacitance between each output terminal to the ground should be less than or equal to 150 pF . This total equivalent capacitance consists of the radio frequency filtering capacitors and ESD protection device equivalent parasitic capacitance.

## NLMD5820



Figure 48. Advanced Optional Audio Output Filter


Figure 49. Optional Audio Output Filter


Figure 50. Optional EMI Ferrite Bead Filter


Figure 51. NLMD5820 Application Schematic with Fully Differential Input Configuration


Figure 52. NLMD5820 Application Schematic with Fully Differential Input Configuration and Ferrite Chip Beads as an Output EMI Filter

## NLMD5820



Figure 53. NLMD5820 Application Schematic with Differential Input Configuration and High Pass Filtering Function


Figure 54. NLMD5820 Application Schematic with Single Ended Input Configuration


Figure 55. NLMD5820 Application Schematic Using Switches as Optional Bypass

## NLMD5820

## PACKAGE DIMENSIONS

## UDFN16 3.2x2.4, 0.4P

CASE 517AL-01
ISSUE O


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